

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet

Part Number/Ordering Information 1/

SDR2

^L Screening ^{₂/}
<pre> = Not Screened</pre>
TX = TX Level
TXV = TXV Level
S = S Level (for SM, use $-S$)
Package Type

SM = Surface Mount Round Tab SMS = Surface Mount Square Tab

Voltage G = 400 V J = 600 V

K = 800 V M = 1000 V

SDR2GSM & SMS

Thru SDR2MSM & SMS

1 AMP ULTRAFAST RECTIFIER 400 – 1000 VOLTS 50 – 70 nsec

FEATURES:

- Ultrafast Recovery: 50-70 ns Max @ 25°C ^{4/} 80-120 ns Max @ 100°C ^{4/}
- PIV to 1000 Volts
- Hermetically Sealed
- Low Reverse Leakage Current
- Single Chip Construction
- For High Efficiency Applications
- Available in Round and Square Tab Versions
- Available in Axial Lead Versions
- TX, TXV, and S-Level Screening Available²/

MAXIMUM RATINGS 3/

RATING		SYMBOL	VALUE	UNIT		
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SDR2G SDR2J SDR2K SDR2M	V _{RRM} V _{RWM} V _R	400 600 800 1000	v		
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A = 25°C)		lo	1	Α		
Peak Surge Current (8.3 msec Pulse, Half Sine Wave Superimposed on Io, allow junction to equilibrium between pulses, $T_A = 25^{\circ}C$)	reach	I _{FSM}	25	Α		
Operating & Storage Temperature		TOP and TSTG	-65 to +175	۵°		
Thermal Resistance, Junction to End Tab		R _{0JE}	28	°C/W		

NOTES:

- 1/ For ordering information, price, operating curves, and availability Contact factory.
- 2/ Screening based on MIL-PRF-19500. Screening flows available on request.
- 3/ Unless otherwise specified, all electrical characteristics @ 25°C.
- <u>4</u>/ Recovery conditions: $I_F = 0.5$ Amp, $I_R = 1.0$ Amp, I_{RR} to .25 Amp.

Surface Mount Round Tab (SM)

Surface Mount Square Tab (SMS)

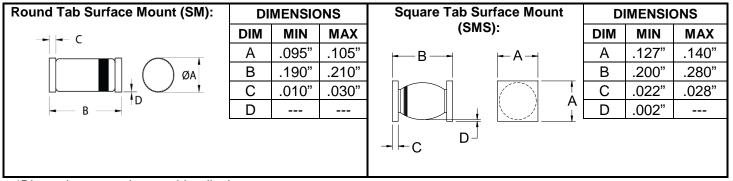




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SDR2GSM & SMS Thru SDR2MSM & SMS

ELECTRICAL CHARACTERISTICS ^{3/}							
CHARACTERIST	SYMBOL	MAXIMUM	UNIT				
	SDR2GSM – SDR2MSM	V _{F1}	2.8	Vdc			
Instantaneous Forward Voltage Drop ($I_F = 1 \text{ Adc}, 300 \ \mu \text{s} \text{ Pulse}, T_A = 25^{\circ}\text{C}$)	SDR2GSMS – SDR2JSMS		1.9				
$(17 - 17)$ (16, 000 μ 01 aloc, $1_A - 20$ O)	SDR2KSMS – SDR2MSMS		2.1				
	SDR2GSM – SDR2MSM	V _{F2}	2.95	Vdc			
Instantaneous Forward Voltage Drop ($I_F = 1 \text{ Adc}, 300 \mu \text{s} \text{ Pulse}, T_A = -55^{\circ}\text{C}$)	SDR2GSMS – SDR2JSMS		2.05				
$(17 - 17, 000, 000, \mu 0, 1000, 1, \Lambda - 00, 0)$	SDR2KSMS – SDR2MSMS		2.25				
Reverse Leakage Current (Rated V _R , 300 μ s Pulse Minimum, T _A = 25°C)	I _{R1}	5	μΑ				
Reverse Leakage Current (Rated V _R , 300 µs Pulse Minimum , T _A = 100°C	I _{R2}	0.5	mA				
Junction Capacitance ($V_R = 10 \text{ Vdc}, T_A = 25^{\circ}\text{C}, f = 1 \text{ MHz}$)	CJ	20	pf				
	SDR2G-JSM & SMS		50	ns			
Reverse Recovery Time ^{4/}	SDR2KSM & SMS	t _{RR}	60				
	SDR2MSM & SMS		70				



*Dimensions are prior to solder dipping

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- <u>4</u>/ Recovery conditions: $I_F = 0.5$ Amp, $I_R = 1.0$ Amp, I_{RR} to 0.25 Amp.